

# iscN-Channel MOSFET Transistor

# IRFBC30A

#### FEATURES

- Low drain-source on-resistance:
  R<sub>DS</sub>(ON) =2.2Ω (MAX)
- Enhancement mode:
  Vth = 2 to 4.5V (VDS = 10 V, ID=0.25mA)
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### DESCRITION

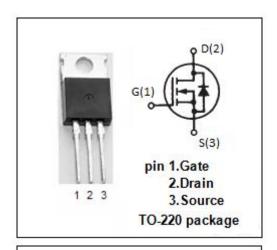
• Switching Voltage Regulators

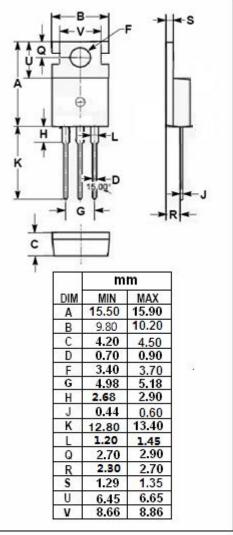
## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	600	V
V <sub>GS</sub>	Gate-Source Voltage	±30	V
I <sub>D</sub>	Drain Current-Continuous	3.6	А
І <sub>ОМ</sub>	Drain Current-Single Pulsed	14	Α
P <sub>D</sub>	Total Dissipation @Tc=25°C	74	W
Tj	Max. Operating Junction Temperature -55^		${\mathbb C}$
T <sub>stg</sub>	Storage Temperature	-55~150	${\mathbb C}$

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	1.7	°C/W







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### **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 0.25mA	600			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = 10V; I <sub>D</sub> =0.25mA	2		4.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =2.2A			2.2	Ω
lgss	Gate-Source Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0V			±100	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =600V; V <sub>GS</sub> = 0V V <sub>DS</sub> =480V; V <sub>GS</sub> = 0V;T <sub>J</sub> =125℃			25 250	μ <b>A</b>
V <sub>SDF</sub>	Diode forward voltage	I <sub>DR</sub> =3.6A, V <sub>GS</sub> = 0 V			1.6	V

#### **NOTICE:**

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